

On the origin of Abrikosov's quantum linear magnetoresistance

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Compensated semimetals with Weyl spectra are predicted to exhibit unsaturated linear growth of their resistivity in quantizing magnetic fields. This so-called quantum linear magnetoresistance was introduced by Abrikosov, but approximations used in the theory remained poorly specified, often causing a confusion about experimental situations in which the analysis is applicable. Here we derive Abrikosov's exact result using an alternative formalism based on diffusion of cyclotron orbits in a random potential. We show that both Weyl spectrum and a disorder smooth on the scale of the magnetic length are essential conditions for the validity of the theory, and the linear magnetoresistance appears in the extreme quantum limit where only the zeroth Landau level is half filled. It is the interplay between the relativistic-like nature of Weyl fermions and the classical dynamics of their cyclotron centers, which leads to the linear magnetoresistance. We also derive an analogous result in two dimensions, which has been missing in the literature and is relevant for numerous graphene-based systems.

INTRODUCTION

In Ref. [1], Abrikosov suggested the model of a compensated Weyl semimetal to explain the linear magnetoresistance in Ref. [2] in the extreme quantum limit, such that $kT \ll \hbar\omega_c$ and $\omega_c\tau \gg 1$, where k is the Boltzmann constant, T is the temperature, ω_c is the cyclotron frequency and τ is the elastic scattering time. This result has often been quoted as an explanation for the linear magnetoresistance of three- and two-dimensional semimetals (see, for example, Refs. [3–5]) and the linear magnetoresistance itself was in turn interpreted as a sign of linear band dispersion even though in some cases the studied experimental systems exhibiting linear magnetoresistance were doped with several Landau levels occupied, clearly beyond the approximations used by Abrikosov. In his original paper, Abrikosov used the formalism of Feynman diagrams in Matsubara imaginary time to calculate the resistivity tensor, while also assuming that the main scatterers were screened ionized impurities. The technique that Abrikosov used somewhat obscured the physical picture behind the linear magnetoresistance. For instance, it makes it look as though the conductivity emerges due to transitions between Landau levels 0 and ± 1 , which in the extreme quantum limit appears counter-intuitive because one would think that in this case all dynamics is restricted to the zeroth Landau level. There are also a number of questions the original derivation does not give the answer to. One of them is to what extent Abrikosov's result applies to two-dimensional semimetals. Its applicability is not entirely obvious because an electron scattering on a screened ionized impurity in three dimensions will have a scattering amplitude and a phase space to scatter into which are vastly different from those in two dimensions.

At the same time, there is a simpler and more intuitive way of calculating magnetoresistivity in the extreme quantum limit, namely, Kubo's center migration theory [6], which treats the current as a result of diffusive motion of cyclotron centers in an external electric field. The formalism is technically equivalent to Abrikosov's theory but has a clear advantage of allowing one to naturally restrict the electron dynamics to a single Landau level. When applied to the calculation of magnetoresistivity of a Weyl semimetal, this method makes it clear that for the linear magnetoresistance to emerge the scattering potential has to be smooth on the scale of $l = \sqrt{\hbar c/eH}$, the magnetic length (where H is the applied magnetic field). In this case one can treat the dynamics of electrons in a classical way and linear magnetoresistance then manifests itself as a purely semiclassical effect, resulting from the interplay between the classical dynamics of orbit centers and the linear-in- H quantum density of states.

The outline of this paper is as follows. In Section I we calculate the magnetoconductivity of three-dimensional Weyl fermions using the quantum-mechanical version of Kubo's center migration theory. In Section II, taking advantage of the smoothness of the scattering potential, we also provide the semiclassical treatment of the same problem. In Section III, we point out the two-dimensional analog of Abrikosov's linear magnetoresistance. In Section IV we demonstrate the equivalence between the center migration theory and the Feynman diagram calculations.

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I. QUANTUM-MECHANICAL TREATMENT

Throughout the paper we set $\hbar = 1$ and restore it in the final equations. Following Abrikosov, we assume that the energy spectrum can be described by a three-dimensional Weyl fermion with the one-body Hamiltonian in the magnetic field in the form

$$\mathcal{H}_0 = v\boldsymbol{\sigma} \cdot \left(\mathbf{p} - \frac{e}{c}\mathbf{A}\right), \quad (1)$$

where v is the Fermi velocity, $\boldsymbol{\sigma} = (\sigma_x, \sigma_y, \sigma_z)$ is a vector of Pauli matrices, \mathbf{A} is the vector potential, e is the electron charge and c is the speed of light. Assume that a magnetic field of magnitude H is applied along the z axis. Then in Landau gauge $\mathbf{A} = (0, Hx, 0)$ and the eigenstates of the Hamiltonian can also be chosen as eigenstates of momenta p_y and p_z . Below, instead of p_y , we will use $X = p_y l^2$ to label the stationary states. The stationary states are also labelled by a third quantum number N taking arbitrary (positive and negative) integer values such that the energy levels have the form $E_N(p_z) = \text{sign}(N)v\sqrt{p_z^2 + 2|N|/l^2}$ for $N \neq 0$ and $E_0(p_z) = vp_z$. The stationary state wavefunctions have the form

$$|NXp_z\rangle = \begin{pmatrix} \frac{1}{\sqrt{2}} \left(1 + \frac{vp_z}{E_N}\right)^{1/2} h_{|N|}(x - X) \\ -\frac{i}{\sqrt{2}} \text{sign}(N) \left(1 - \frac{vp_z}{E_N}\right)^{1/2} h_{|N|-1}(x - X) \end{pmatrix} \frac{e^{iyX/l^2 + ip_z z}}{\sqrt{L_y L_z}} \quad (2)$$

for $N \neq 0$ and

$$|0Xp_z\rangle = \begin{pmatrix} h_0(x - X) \\ 0 \end{pmatrix} \frac{e^{iyX/l^2 + ip_z z}}{\sqrt{L_y L_z}} \quad (3)$$

for $N = 0$, where $h_{|N|}(x) = (2^{|N|}|N|!\sqrt{\pi}l)^{-1/2} H_{|N|}(x/l) \exp[-x^2/(2l^2)]$ is the level $|N|$ quantum oscillator stationary state, with $H_{|N|}(x/l)$ the Hermite polynomial. In Landau gauge, the stationary states in each Landau level are localized in the planes $x = X$, where X is the cyclotron center position along x . For a finite sample with dimensions $L_x \times L_y \times L_z$, the quantum number X takes values between 0 and L_x in steps of $2\pi l^2/L_y$. Since the energy levels do not depend on X , the degeneracy of each Landau level equals $L_x/(2\pi l^2/L_y) = L_x L_y/(2\pi l^2)$. One can also define the cyclotron center position along y as $Y = y - l^2 p_x$, but $[X, Y] = -il^2$ so X and Y do not commute and stationary states cannot be eigenstates of both.

When the semimetal is fully compensated, *i.e.*, the densities of conduction electrons and holes are equal to each other and the chemical potential μ vanishes, the Hall conductivity σ_{xy} vanishes too. Below we will assume full compensation and will be interested in calculating σ_{xx} . In the limit of high enough magnetic field, such that $kT \ll \omega_c$, where $\omega_c = \sqrt{2}v/l$, the carriers are mostly confined to the zeroth Landau level and, being localized around their cyclotron centers, have zero kinetic energy of motion in the xy plane. When an electric field is applied along x , the carriers will start moving along y , which will result in a Hall current, vanishing when the densities of electrons and holes are equal to each other. To make electrons move along the electric field, one has to introduce scatterers that will make electrons hop between cyclotron centers performing a random walk. Then the longitudinal conductivity σ_{xx} is related to the diffusion coefficient D_{xx} associated with this random walk through Einstein relation

$$\sigma_{xx} = e^2 \left(\frac{\partial n}{\partial \mu}\right) D_{xx}, \quad (4)$$

where

$$\frac{\partial n}{\partial \mu} = \int d\varepsilon \nu(\varepsilon) \left(-\frac{\partial f}{\partial \varepsilon}\right) \quad (5)$$

with $f(\varepsilon) = \{\exp[(\varepsilon - \mu)/(kT)] + 1\}^{-1}$ the Fermi-Dirac distribution and $\nu(\varepsilon)$ the density of states per unit volume defined as

$$\nu(\varepsilon) = \frac{2}{V} \sum_{Xp_z} \delta[\varepsilon - E_0(p_z)], \quad (6)$$

where $V = L_z L_y L_x$ is the volume of the sample, a factor of 2 accounts for spin and we also took into account that the contribution of the other Landau levels to $\partial n / \partial \mu$ apart from $N = 0$ is exponentially small. The diffusion coefficient equals

$$D_{xx} = \frac{1}{2} \sum_{p'_z X'} \frac{(X' - X)^2}{\tau_{Xp_z \rightarrow X'p'_z}}, \quad (7)$$

where $\tau_{Xp_z \rightarrow X'p'_z}$ is the inverse transition rate between states $|0Xp_z\rangle$ and $|0X'p'_z\rangle$ (here we also neglected scattering between different Landau levels). When the scattering events are rare, *i.e.*, $\omega_c \tau \gg 1$ one can use the Fermi golden rule to evaluate the transition rate

$$\frac{1}{\tau_{Xp_z \rightarrow X'p'_z}} = 2\pi \langle | \langle 0X'p'_z | U | 0Xp_z \rangle |^2 \rangle_s \delta[E_0(p_z) - E_0(p'_z)], \quad (8)$$

where U is the scattering potential and $\langle \dots \rangle_s$ stands for averaging over the positions of scatterers. If we substitute Eqs. (5)–(8) into Eq. (4) we will obtain

$$\sigma_{xx} = \frac{2e^2}{V} \sum_{Xp_z} \sum_{X'p'_z} \left(-\frac{\partial f}{\partial \varepsilon} \right) \Big|_{\varepsilon=E_0(p_z)} \frac{(X - X')^2}{2} 2\pi \langle | \langle 0Xp_z | U | 0X'p'_z \rangle |^2 \rangle_s \delta[E_0(p_z) - E_0(p'_z)], \quad (9)$$

which is one of the central equations of the center migration theory, see [6]. Let us now evaluate the diffusion coefficient given by Eqs. (7)–(8). The scattering potential U is a sum of potentials created by different impurities

$$U(\mathbf{r}) = \sum_{\mathbf{R}_i} u(\mathbf{r} - \mathbf{R}_i), \quad (10)$$

where $u(\mathbf{r}) = (1/V) \sum_{\mathbf{q}} u_{\mathbf{q}} \exp(i\mathbf{q}\mathbf{r})$ is the potential created by an impurity sitting at the origin and \mathbf{R}_i is the position of each impurity. Assuming uniform impurity distribution and keeping only the term linear in the impurity concentration we obtain

$$\langle U(\mathbf{r})U(\mathbf{r}') \rangle_s = \frac{N_s}{V} \sum_{\mathbf{q}} |u_{\mathbf{q}}|^2 e^{i\mathbf{q}(\mathbf{r}-\mathbf{r}')}, \quad (11)$$

where N_s is the impurity concentration. Let us evaluate the square of the transition matrix (recall that $X = p_y l^2$)

$$\begin{aligned} \langle | \langle 0Xp_z | U | 0X'p'_z \rangle |^2 \rangle_s &= \frac{N_s}{V} \sum_{\mathbf{q}} |u_{\mathbf{q}}|^2 | \langle 0Xp_z | e^{i\mathbf{q}\mathbf{r}} | 0X'p'_z \rangle |^2 \\ &= \frac{N_s}{V} \sum_{\mathbf{q}} |u_{\mathbf{q}}|^2 \delta_{X'-X+q_y l^2, 0} \delta_{p'_z - p_z + q_z, 0} \left| \frac{1}{\sqrt{\pi}l} \int dx e^{-(x-X)^2/(2l^2)} e^{iq_x x} e^{-(x-X')^2/(2l^2)} \right|^2 \\ &= \frac{N_s}{V} \sum_{\mathbf{q}} |u_{\mathbf{q}}|^2 \delta_{X'-X+q_y l^2, 0} \delta_{p'_z - p_z + q_z, 0} e^{-q_{\perp}^2 l^2/2}, \end{aligned} \quad (12)$$

where $q_{\perp}^2 = q_x^2 + q_y^2$. Substituting this back into Eqs. (7)–(8) and performing summation with respect to X' and p'_z we obtain

$$D_{xx} = \frac{1}{V} \sum_{\mathbf{q}} \frac{(q_y l^2)^2}{2} 2\pi N_s |u_{\mathbf{q}}|^2 e^{-q_{\perp}^2 l^2/2} \delta[E_0(p_z) - E_0(p_z - q_z)]. \quad (13)$$

Let us change in this equation summation with respect to \mathbf{q} to integration according to the rule

$$\sum_{\mathbf{q}} \cdots = V \int \frac{d^3 q}{(2\pi)^3} \cdots \quad (14)$$

and also substitute $E_0(p_z) = vp_z$. This results in

$$D_{xx} = \int \frac{d^3 q}{(2\pi)^3} \frac{(q_y l^2)^2}{2} 2\pi N_s |u_{\mathbf{q}}|^2 e^{-q_{\perp}^2 l^2 / 2} \delta(vq_z) = \frac{1}{v} \int \frac{d^2 q_{\perp}}{(2\pi)^2} \frac{(q_y l^2)^2}{2} N_s e^{-q_{\perp}^2 l^2 / 2} |u_{\mathbf{q}}|^2 \Big|_{q_z=0}. \quad (15)$$

The compressibility $\partial n / \partial \mu$, given by Eqs. (5)–(6), equals at $\mu = 0$

$$\frac{\partial n}{\partial \mu} = \frac{2}{V} \sum_{X p_z} \left(-\frac{\partial f}{\partial \varepsilon} \right) \Big|_{\varepsilon=E_0(p_z)} = \frac{2}{(2\pi l^2) L_x} \int_0^{L_x} dX \int \frac{dp_z}{(2\pi)} \left(-\frac{\partial f}{\partial \varepsilon} \right) \Big|_{\varepsilon=E_0(p_z)}, \quad (16)$$

where we changed summation with respect to X and p_z to integration according to the rules

$$\sum_X \cdots = \frac{L_y}{2\pi l^2} \int_0^{L_x} dX \cdots; \quad \sum_{p_z} \cdots = L_z \int \frac{dp_z}{2\pi} \cdots \quad (17)$$

Performing the trivial integral with respect to X , we obtain

$$\frac{\partial n}{\partial \mu} = \frac{1}{2\pi l^2} 2 \int \frac{dp_z}{2\pi} \left(-\frac{\partial f}{\partial \varepsilon} \right) \Big|_{\varepsilon=E_0(p_z)} = \frac{2}{2\pi l^2} \int \frac{dp_z}{2\pi kT} \frac{1}{(e^{vp_z/(2kT)} + e^{-vp_z/(2kT)})^2} = \frac{2}{(2\pi)^2 l^2 v}. \quad (18)$$

Plugging Eqs. (18) and (15) into Eq. (4), we obtain

$$\sigma_{xx} = \frac{2e^2}{(2\pi)^2 l^2 v^2} \int \frac{d^2 q_{\perp}}{(2\pi)^2} \frac{(q_y l^2)^2}{2} N_s e^{-q_{\perp}^2 l^2 / 2} |u_{\mathbf{q}}|^2 \Big|_{q_z=0}. \quad (19)$$

Note that, if the potential is sufficiently smooth, that is to say if $|u_{\mathbf{q}}|^2 \Big|_{q_z=0}$ goes to zero faster than $\exp(-q_{\perp}^2 l^2 / 2)$ as $q_{\perp} \rightarrow \infty$, then the exponential can be neglected in the integrand of Eq. (19). Then, the magnetic field dependence of σ_{xx} derives from the factor l^4 due to the diffusion constant and from the factor l^{-2} that came from the density of states so that in the end $\sigma_{xx} \propto l^2 \propto 1/H$ and $\rho_{xx} = 1/\sigma_{xx} \propto H$. To see this in more detail let us, following Abrikosov, take charged partially screened impurities as primary scatterers. Then

$$u_{\mathbf{q}} = \frac{4\pi e^2}{\epsilon_{\infty}(q^2 + \kappa^2)}, \quad (20)$$

where $q^2 = q_{\perp}^2 + q_z^2$ is transmitted momentum squared, ϵ_{∞} is the effective dielectric constant and κ^2 is the Thomas-Fermi inverse screening length given by the equation

$$\kappa^2 = \frac{4\pi e^2}{\epsilon_{\infty}} \frac{\partial n}{\partial \mu} = \frac{2e^2}{\pi \epsilon_{\infty} v l^2}. \quad (21)$$

If $e^2/(\epsilon_{\infty} v) \ll 1$ then $\kappa^2 \ll 1/l^2$. Let us evaluate Eq. (19). Note that q_y^2 there can be changed to $q_{\perp}^2/2$ due to cylindrical symmetry of the potential while $q_z = 0$. We then obtain

$$\sigma_{xx} = 2e^2 l^2 \left(\frac{e^2}{v \epsilon_{\infty}} \right)^2 N_s \int \frac{d^2 q_{\perp}}{(2\pi)^2} \frac{q_{\perp}^2}{(q_{\perp}^2 + \kappa^2)^2} e^{-q_{\perp}^2 l^2 / 2}. \quad (22)$$

Without the exponential, the integral in Eq. (22) diverges logarithmically. The exponential then imposes a high-momentum cut-off on the order of $1/l$ on which the integral will depend logarithmically. On the other hand, the integral also diverges logarithmically at low momenta without κ^2 in the denominator. So κ imposes a low-momentum cut-off, on which the integral will depend logarithmically too. Ultimately the value of the integral will be on the order of $\ln(\kappa l)$ and the dependence on l will cancel between the low and the high momentum cut-off. Thus, to logarithmic accuracy, the integral evaluates to

$$\sigma_{xx} = \frac{e^2}{2\pi\hbar} l^2 \left(\frac{e^2}{\hbar v \epsilon_\infty} \right)^2 N_s \ln \left(\frac{1}{\kappa^2 l^2} \right) = \frac{e^2}{2\pi\hbar} l^2 \left(\frac{e^2}{\hbar v \epsilon_\infty} \right)^2 N_s \ln \left(\frac{\epsilon_\infty v \hbar}{e^2} \right) \propto 1/H, \quad (23)$$

where we also restored \hbar . This is exactly Abrikosov's result [1].

II. SEMICLASSICAL EVALUATION

The same result could be obtained from classical dynamics. Basically, what happens is this: when an electron passes an impurity with velocity v along the magnetic field the center of its orbit is deflected in the plane perpendicular to the field. Because the motion along the magnetic field is unidirectional (see below) the electron never returns to the same impurity and localization effects can be neglected. Let us consider the motion of an electron in the force field of an impurity more precisely. Including the impurity potential in Eq. (1), the Hamiltonian has the form

$$\mathcal{H} = v\boldsymbol{\sigma} \cdot \left(\mathbf{p} - \frac{e}{c} \mathbf{A} \right) + u(\mathbf{r}), \quad (24)$$

where $u(\mathbf{r})$ is the potential of a single impurity sitting at the origin. The coordinates ξ_x and ξ_y that describe the relative motion of the electron with respect to the cyclotron center are defined as

$$\xi_x = -l^2 \left(p_y - \frac{e}{c} A_y \right); \quad \xi_y = l^2 \left(p_x - \frac{e}{c} A_x \right), \quad (25)$$

while the coordinates X and Y of the cyclotron center are defined as

$$X = x - \xi_x; \quad Y = y - \xi_y. \quad (26)$$

The operators thus introduced have the following commutation relations among each other

$$\begin{aligned} [\xi_x, \xi_y] &= il^2; & [X, Y] &= -il^2; \\ [X, \xi_x] &= [X, \xi_y] = [Y, \xi_x] = [Y, \xi_y] = 0, \end{aligned} \quad (27)$$

and they all obviously commute with z and p_z and also pseudospin. The equations of motion for X and Y read

$$\dot{X} = i[\mathcal{H}, X] = l^2 \partial_y u(\mathbf{r}); \quad \dot{Y} = i[\mathcal{H}, Y] = -l^2 \partial_x u(\mathbf{r}), \quad (28)$$

where we took into account that $[X, y] = [X, Y + \xi_y] = -il^2$ and $[Y, x] = [Y, X + \xi_x] = il^2$. Let us restrict the dynamics to the zeroth Landau level. In this case it is not difficult to show that the uncertainty in the values of ξ_x and ξ_y reaches the value of $l/\sqrt{2}$. Therefore if the potential is smooth on the scale of l , one can neglect the difference between x and X and between y and Y on the right hand side of Eq. (28) and close the equations of motion with respect to X and Y . On the other hand, as follows from the commutation relation between X and Y , the uncertainty in the values of X and Y can be made as small as l . Therefore, for a smooth potential, instead of the Heisenberg equations of motion one can consider classical dynamics of point particles located at $\mathbf{R} = (X, Y)$. The equations of motion for them will have the form

$$\dot{X} = l^2 \partial_Y u(\mathbf{R}); \quad \dot{Y} = -l^2 \partial_X u(\mathbf{R}); \quad \dot{z} = \frac{\partial E_0(p_z)}{\partial p_z} = v, \quad (29)$$

where v is the Fermi velocity. For simplicity, let us assume the potential to be spherically symmetric. Then

$$\dot{X} = l^2(Y/\rho)\partial_\rho u; \quad (30)$$

$$\dot{Y} = -l^2(X/\rho)\partial_\rho u, \quad (31)$$

where $\rho = \sqrt{X^2 + Y^2}$ is the radial coordinate. If we multiply the first equation by X and the second by Y and take their sum we will get

$$X\dot{X} + Y\dot{Y} = \frac{1}{2} \frac{d(\rho^2)}{dt} = 0, \quad (32)$$

which means that the radial coordinate remains the same. This is not surprising since we know that the drift of the cyclotron center must happen in the direction perpendicular to the force exerted by the impurity. So what happens is that the polar angle changes. Introducing the polar angle in the form

$$X = \rho \cos \phi; \quad (33)$$

$$Y = \rho \sin \phi \quad (34)$$

and substituting this into the equations of motion we obtain

$$\dot{\phi} = -(l^2/\rho)\partial_\rho u. \quad (35)$$

Therefore the total change in the angle as the particle passes the impurity is equal to

$$\Delta\phi = - \int_{-\infty}^{\infty} dt (l^2/\rho)\partial_\rho u. \quad (36)$$

Recall that $\dot{z} = v$, so that the integral with respect to t can be changed to the integral with respect to z in the following manner

$$\Delta\phi = -\frac{1}{v} \int_{-\infty}^{\infty} dz (l^2/\rho)\partial_\rho u. \quad (37)$$

Now imagine an electron incident on an impurity with an initial polar angle ϕ_1 . After it scatters off the impurity it will have a different polar angle $\phi_2 = \phi_1 + \Delta\phi$. The impact parameter ρ (*i.e.* the distance from the impurity) will not change. The shift of the position of the center of the orbit is expressed then by the equations

$$\Delta X = \rho(\cos \phi_2 - \cos \phi_1); \quad (38)$$

$$\Delta Y = \rho(\sin \phi_2 - \sin \phi_1). \quad (39)$$

On average, both shifts are equal to zero. But what will not be averaged to zero is the mean squared shift

$$(\Delta X)^2 + (\Delta Y)^2 = 2\rho^2(1 - (\cos \phi_2 \cos \phi_1 + \sin \phi_2 \sin \phi_1)) = 2\rho^2(1 - \cos(\phi_2 - \phi_1)) = 2\rho^2(1 - \cos \Delta\phi). \quad (40)$$

Assuming $\Delta\phi \ll 1$ we obtain

$$(\Delta X)^2 + (\Delta Y)^2 = \rho^2(\Delta\phi)^2. \quad (41)$$

At small impurity density, the scattering events on different impurities are uncorrelated and the total scattering rate equals $N_s v(d\sigma/d\rho)$ per unit impact parameter, where $d\sigma$ is the differential cross-section and N_s is the impurity density, so the diffusion coefficient is then equal to

$$\begin{aligned}
D_{xx} &= \frac{1}{2}(D_{xx} + D_{yy}) = \frac{1}{2} \int d\rho N_s v \frac{d\sigma}{d\rho} \frac{(\Delta X)^2 + (\Delta Y)^2}{2} \\
&= \frac{1}{4} \int N_s v \frac{d\sigma}{d\rho} \rho^2 (\Delta\phi)^2 d\rho = \frac{1}{2} \pi N_s \int \rho d\rho v^{-1} l^4 \left(\int_{-\infty}^{+\infty} dz \partial_\rho u \right)^2, \tag{42}
\end{aligned}$$

where we just substituted $(d\sigma/d\rho) = 2\pi\rho$. This integral is the same as the one on the right hand side of Eq. (19), only without the exponential $\exp[-q_\perp^2 l^2/2]$ and written in the coordinate representation. The exponential is a sign of finite spread of the electron's wavefunction so it is not surprising that it does not appear in the classical treatment. For completeness let us calculate the integral in Eq. (42) in the coordinate representation too. Take the screened Coulomb potential

$$u(\rho, z) = \frac{e^2 e^{-\kappa\sqrt{\rho^2+z^2}}}{\epsilon_\infty \sqrt{\rho^2+z^2}}, \tag{43}$$

where κ is the inverse screening length calculated in Eq. (21) and ϵ_∞ is the effective dielectric constant. For ρ greater than the screening length $1/\kappa$ the electron does not feel the scattering potential so that we can impose the upper limit on ρ at $1/\kappa$ in the integral above and neglect the screening for $\rho < 1/\kappa$. On the other hand, the characteristic length scale on which the unscreened Coulomb potential changes significantly is just the distance to the origin and in close proximity to the origin it changes very fast. Therefore, at distances to the origin smaller than l the semiclassical approximation breaks down and therefore we have to impose a lower cut-off on ρ at l in Eq. (42). We might of course have got away without it, if the integral were convergent at small values of ρ , but it is not, it is in fact logarithmically divergent. Thus the diffusion constant is equal to

$$\begin{aligned}
D_{xx} &= \frac{1}{2} \pi N_s \int_l^{1/\kappa} \rho d\rho v^{-1} l^4 \left(\int_{-\infty}^{+\infty} dz \frac{e^2 \rho}{\epsilon_\infty (\rho^2+z^2)^{3/2}} \right)^2 \\
&= 2\pi N_s \frac{e^4 l^4}{\epsilon_\infty^2 v} \int_l^{1/\kappa} \frac{d\rho}{\rho} = 2\pi N_s \frac{e^4 l^4}{\epsilon_\infty^2 v} \ln \left(\frac{1}{\kappa l} \right) = \pi N_s \frac{e^4 l^4}{\epsilon_\infty^2 v} \ln \left(\frac{\epsilon_\infty v}{e^2} \right). \tag{44}
\end{aligned}$$

Now, by Einstein relation

$$\sigma_{xx} = e^2 (\partial n / \partial \mu) D_{xx} = e^2 \frac{2}{(2\pi)^2 l^2 v} \pi N_s \frac{e^4 l^4}{\epsilon_\infty^2 v} \ln \left(\frac{\epsilon_\infty v}{e^2} \right) = \frac{e^2}{2\pi} l^2 \left(\frac{e^2}{\epsilon_\infty v} \right)^2 N_s \ln \left(\frac{\epsilon_\infty v}{e^2} \right), \tag{45}$$

where $\partial n / \partial \mu$ was calculated in Eq. (18). Note again that the resulting dependence on l comes from the interplay between the classical dynamics of Eq. (29) and the quantum-mechanical density of states in Eq. (18). This result is exactly the same as the one given in Eq. (22).

III. CENTER MIGRATION IN TWO DIMENSIONS

In this section we will apply center migration theory to a two-dimensional semimetal in a smooth static disorder potential. Here we will be following the treatment for a non-relativistic electron gas presented in Refs. [6, 7]. Consider a fully compensated graphene sheet ($\mu = 0$) in a magnetic field H applied perpendicularly to the plane of motion. The low energy excitations can be effectively described by four independent Dirac Hamiltonians, corresponding to two inequivalent valleys each with two opposite spin orientations. We will only consider a single Dirac fermion and multiply its contribution to the conductivity by four. The Hamiltonian for a two-dimensional Dirac fermion in magnetic field has the form

$$\mathcal{H}_0 = v \boldsymbol{\sigma} \cdot \left(\mathbf{p} - \frac{e}{c} \mathbf{A} \right), \tag{46}$$

where now $\boldsymbol{\sigma} = (\sigma_x, \sigma_y)$. In Landau gauge $\mathbf{A} = (0, Hx, 0)$ corresponding to a magnetic field of magnitude H applied along z . In Landau gauge the stationary states can be chosen as eigenstates of the operator X , and therefore they are labelled by values of their cyclotron center position along x as well as by a Landau level number N taking (positive and negative) integer values. The energy levels are equal to $E_N = \text{sign}(N)\omega_c\sqrt{|N|}$, where $\omega_c = \sqrt{2}v/l$ and the stationary states are, for $N \neq 0$,

$$|NX\rangle = \begin{pmatrix} \frac{1}{\sqrt{2}}h_{|N|}(x-X) \\ -\frac{i}{\sqrt{2}}\text{sign}(N)h_{|N|-1}(x-X) \end{pmatrix} \frac{e^{iXy/l^2}}{\sqrt{L_y}} \quad (47)$$

and, for $N = 0$,

$$|0X\rangle = \begin{pmatrix} h_0(x-X) \\ 0 \end{pmatrix} \frac{e^{iXy/l^2}}{\sqrt{L_y}}. \quad (48)$$

Here again $h_{|N|}(x-X) = (2^{|N|}|N|!\sqrt{\pi}l)^{-1/2}H_{|N|}[(x-X)/l] \exp[-(x-X)^2/(2l^2)]$ is the $|N|$ -th energy level stationary state of a harmonic oscillator shifted by X away from the origin, L_y is the dimension of the sample along y , the dimension along x being L_x . The cyclotron center position X takes values between 0 and L_x in steps of $2\pi l^2/L_y$. We will again assume a smooth static disorder. This can be created by charged impurities residing outside the plane of motion, e.g. in the substrate. At temperatures satisfying $kT \ll \omega_c$ all the charge carriers (electrons and holes) reside in the zeroth Landau level so we can restrict all the dynamics to it.

We will again apply the central equation of the center migration theory, Eq. (9), only this time there is no quantum number p_z . This creates a problem because $\delta(E_0 - E_0)$ is infinity. The root of the problem is that the unperturbed Landau levels are infinitely thin. To cure that we just have to take into account the broadening. This is achieved by the substitution

$$\left(-\frac{\partial f}{\partial \varepsilon}\right) \Big|_{\varepsilon=E_0} \delta(E_0 - E_0) \rightarrow \int d\varepsilon \left(-\frac{\partial f}{\partial \varepsilon}\right) \langle S_{0X}(\varepsilon) \rangle_s \langle S_{0X'}(\varepsilon) \rangle_s, \quad (49)$$

where S_{NX} is the spectral function of the N th Landau level defined as

$$S_{NX}(\varepsilon) = \langle NX | \delta(\varepsilon - \mathcal{H}) | NX \rangle = -\frac{1}{\pi} \text{Im} G_{NX}(\varepsilon + i0), \quad (50)$$

where $\mathcal{H} = \mathcal{H}_0 + U(\mathbf{r})$ is the Dirac Hamiltonian perturbed by the disorder potential $U(\mathbf{r})$. In the equation above, G_{NX} is the Green function of the electron in the N th Landau level in presence of disorder.

Therefore, taking the broadening in Eq. (49) into account we obtain

$$\sigma_{xx} = \frac{4e^2}{V} \sum_X \sum_{X'} \int d\varepsilon \left(-\frac{\partial f}{\partial \varepsilon}\right) \frac{(X-X')^2}{2} 2\pi \langle | \langle 0X | U | 0X' \rangle |^2 \rangle_s \langle S_{0X}(\varepsilon) \rangle_s \langle S_{0X'}(\varepsilon) \rangle_s, \quad (51)$$

where a factor of 4 takes account of the spin and valley degeneracy, and $V = L_x L_y$ is the area of the sample.

We will assume Gaussian disorder with correlation function

$$\langle U(\mathbf{r})U(\mathbf{r}') \rangle_s = \mathcal{F}(\mathbf{r} - \mathbf{r}') = \frac{1}{V} \sum_{\mathbf{q}} \mathcal{F}_{\mathbf{q}} e^{i\mathbf{q}(\mathbf{r}-\mathbf{r}')}, \quad (52)$$

where

$$\mathcal{F}(\mathbf{r} - \mathbf{r}') = U_0^2 \exp\left(-\frac{|\mathbf{r} - \mathbf{r}'|^2}{2\xi^2}\right); \quad \mathcal{F}_{\mathbf{q}} = 2\pi U_0^2 \xi^2 \exp\left(-\frac{\mathbf{q}^2 \xi^2}{2}\right), \quad (53)$$

where U_0 is the characteristic strength and ξ is the correlation length of the disorder potential.

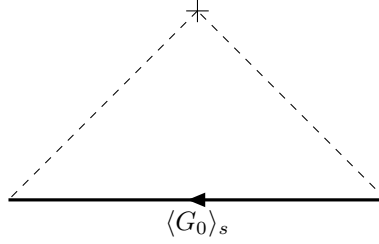


FIG. 1. Self-energy of the zeroth Landau level in the self-consistent Born approximation

Note that due to translational symmetry of the disorder correlation function (53), the disorder-averaged spectral function $\langle S_{0X}(\varepsilon) \rangle_s$ will not depend on X , so we drop this dependence in subsequent equations. Calculating the disorder averaged of the square of transition matrix element in Eq. (51), we obtain

$$\sigma_{xx} = 4e^2 \frac{1}{V} \sum_X \frac{1}{V} \sum_{\mathbf{q}} \left(-\frac{\partial f}{\partial \varepsilon} \right) \frac{(q_y l^2)^2}{2} 2\pi \mathcal{F}_{\mathbf{q}} e^{-q^2 l^2 / 2} \langle S_0(\varepsilon) \rangle_s \langle S_0(\varepsilon) \rangle_s. \quad (54)$$

Taking into account the rotational symmetry of $\mathcal{F}_{\mathbf{q}}$ let us replace q_y^2 with $q^2/2$. Also replacing summations with respect to quantum numbers with integrals according to the rules

$$\sum_{\mathbf{q}} \cdots \rightarrow V \int \frac{d^2 q}{(2\pi)^2} \cdots; \quad \sum_X \cdots \rightarrow \frac{L_y}{2\pi l^2} \int_0^{L_x} dX \cdots \quad (55)$$

and performing the integration over X we obtain

$$\sigma_{xx} = e^2 l^2 \int d\varepsilon \left(-\frac{\partial f}{\partial \varepsilon} \right) \langle S_0(\varepsilon) \rangle_s^2 \int \frac{d^2 q}{(2\pi)^2} \mathcal{F}_{\mathbf{q}} q^2 e^{-q^2 l^2 / 2}. \quad (56)$$

Because the unperturbed Landau levels have zero width, the broadening must be calculated self-consistently. The self-energy $\langle \Sigma_0(\varepsilon) \rangle_s$ is thus defined via the self-consistent equations (see Fig. 1)

$$\begin{aligned} \langle \Sigma_0(\varepsilon) \rangle_s &= \frac{\gamma^2}{4} \langle G_0(\varepsilon) \rangle_s, \\ \langle G_0(\varepsilon) \rangle_s &= \frac{1}{\varepsilon - \langle \Sigma_0(\varepsilon) \rangle_s}, \end{aligned} \quad (57)$$

where $\langle G_0(\varepsilon) \rangle_s$ is the disorder-averaged zeroth Landau level Green function and

$$\frac{\gamma^2}{4} = \int \frac{d^2 q}{(2\pi)^2} \mathcal{F}_{\mathbf{q}} e^{-q^2 l^2 / 2}. \quad (58)$$

In Eq. (57) we have neglected diagrams with self-intersecting impurity lines (the resulting approximation is called the self-consistent Born approximation). Thus, the following equation follows

$$\langle \Sigma_0(\varepsilon) \rangle_s = \frac{\gamma^2}{4} \frac{1}{\varepsilon - \langle \Sigma_0(\varepsilon) \rangle_s}, \quad (59)$$

The quadratic equation (59) has the following solution

$$\langle \Sigma_0(\varepsilon) \rangle_s = \frac{\varepsilon}{2} - i \sqrt{\frac{\gamma^2}{4} - \frac{\varepsilon^2}{4}}. \quad (60)$$

From this, one can see that γ is the width of the zeroth Landau level. Taking the imaginary part of the disorder averaged Green function given by Eqs. (57) and (60), we obtain

$$\langle S_0(\varepsilon) \rangle_s^2 = \frac{4}{\pi^2 \gamma^2} \left(1 - \frac{\varepsilon^2}{\gamma^2} \right). \quad (61)$$

Plugging this into Eq. (56), we obtain

$$\sigma_{xx} = \frac{4e^2 l^2}{\pi^2 \gamma^2} \int d\varepsilon \left(-\frac{\partial f}{\partial \varepsilon} \right) \left(1 - \frac{\varepsilon^2}{\gamma^2} \right) \int \frac{d^2 q}{(2\pi)^2} \mathcal{F}_{\mathbf{q}} l^2 q^2 e^{-q^2 l^2 / 2}. \quad (62)$$

Introducing the transport scattering rate γ_{tr} as

$$\frac{\gamma_{tr}^2}{4} = \int \frac{d^2 q}{(2\pi)^2} \mathcal{F}_{\mathbf{q}} l^2 q^2 e^{-q^2 l^2 / 2}, \quad (63)$$

one can rewrite this equation as

$$\sigma_{xx} = \frac{e^2}{\pi^2} \int d\varepsilon \left(-\frac{\partial f}{\partial \varepsilon} \right) \left(1 - \frac{\varepsilon^2}{\gamma^2} \right) \frac{\gamma_{tr}^2}{\gamma^2}. \quad (64)$$

Using the disorder correlation function (53), and taking the limit of extremely large correlation length $\xi \gg l$, we obtain

$$\frac{\gamma_{tr}^2}{\gamma^2} = \frac{2l^2}{\xi^2}. \quad (65)$$

The integral in Eq. (64) with respect to ε depends only weakly on temperature if $\gamma > kT$. Under this assumption we obtain (restoring \hbar)

$$\sigma_{xx} = \frac{e^2}{\pi^2 \hbar} \frac{2l^2}{\xi^2} \propto \frac{1}{H}. \quad (66)$$

IV. EQUIVALENCE OF FEYNMAN DIAGRAMS AND CENTER MIGRATION EQUATIONS

In this section we demonstrate that the center migration theory is equivalent to the usual Feynman diagrams. We will do this for the three-dimensional model and the generalization to the two dimensional case will be obvious. The treatment here will be very close to that of Ref. [7].

In linear response theory the static conductivity tensor is given by the equation

$$\sigma_{ik} = - \lim_{\omega \rightarrow 0} \frac{\Im Q_{ik}^R(\omega)}{\omega}, \quad (67)$$

where $Q_{ik}^R(\omega)$ is the Fourier transform of the current-current linear response function

$$Q_{ik}^R(\omega) = -iV^{-1} \int_0^\infty dt e^{i\omega t} \langle [j_i(t), j_k(0)] \rangle, \quad (68)$$

where j_i is the many-body current operator and the brackets $\langle \dots \rangle$ stand for thermal averaging. The function $Q_{ik}^R(\omega)$ can in turn be obtained by analytic continuation from discrete imaginary frequencies of $Q_{ik}(i\omega_m)$, which is the Fourier transform of the imaginary time current-current correlation function,

$$Q_{ik}(i\omega_m) = -V^{-1} \int_0^{1/T} d\tau e^{i\omega_m \tau} \langle T_\tau j_i(\tau) j_k(0) \rangle, \quad (69)$$

where $\omega_m = 2\pi mT$ with m integer, and T_τ stands for time ordering in imaginary time. The function $Q_{ik}(i\omega_m)$ can be represented as a sum of connected diagrams with the two operator insertions $j_i = ev \int d\mathbf{r} \psi^\dagger \sigma_i \psi$ and $j_k = ev \int d\mathbf{r} \psi^\dagger \sigma_k \psi$, where ψ is the electron field operator.

The diagrams that contribute to conductivity σ_{xx} in the first Born approximation and to the first non-trivial order in powers of ω_c^{-1} are depicted in Fig. 2. The Green functions corresponding to fermion lines are disorder averaged and because, as we will see, disorder couples Landau levels with equal but opposite Landau level numbers, each line is labelled not by the Landau level number but by the absolute Landau level number. The reasoning behind this choice of diagrams is as follows. Because the chemical potential is zero and the temperature is low such that $kT \ll \omega_c$, the diagrams that give the largest contribution must have as many Landau level zero internal lines as possible. Each internal line that is other than Landau level zero brings in an additional power of ω_c^{-1} . On the other hand, since the current operator σ_x couples Landau levels with numbers differing by ± 1 , some of the states propagating along internal lines must have absolute Landau level number equal to one.

The proper four-fermion vertex part used in the first Born approximation, depicted in Fig. 3 (a), equals

$$\left\langle \langle N' X' p'_z | U | N X p_z \rangle \langle N''' X''' p'''_z | U | N'' X'' p''_z \rangle \right\rangle_s = \frac{1}{V} \sum_{\mathbf{q}} N_s |u_{\mathbf{q}}|^2 \langle N' X' p'_z | e^{i\mathbf{q}\mathbf{r}} | N X p_z \rangle \langle N''' X''' p'''_z | e^{-i\mathbf{q}\mathbf{r}} | N'' X'' p''_z \rangle, \quad (70)$$

where

$$\begin{aligned} \langle N' X' p'_z | e^{i\mathbf{q}\mathbf{r}} | N X p_z \rangle &= \delta_{X', X+q_y l^2} \delta_{p'_z, p_z + q_z} \exp \left[i q_x \frac{(X + X')}{2} + i\varphi (|N'| - |N|) \right] \\ &\times \left\{ \frac{1}{2} \left(1 + \frac{v p'_z}{E_{N'}} \right)^{1/2} \left(1 + \frac{v p_z}{E_N} \right)^{1/2} L_{|N'|, |N|} \left(\frac{q_\perp l}{\sqrt{2}} \right) \right. \\ &\quad \left. + \frac{1}{2} \text{sign}(N') \text{sign}(N) \left(1 - \frac{v p'_z}{E_{N'}} \right)^{1/2} \left(1 - \frac{v p_z}{E_N} \right)^{1/2} L_{|N'|-1, |N|-1} \left(\frac{q_\perp l}{\sqrt{2}} \right) \right\} \end{aligned} \quad (71)$$

for $N \neq 0$ and $N' \neq 0$, with the polar angle $\varphi = \arg(q_x + iq_y)$ and

$$L_{n', n}(x) = L_{n, n'}(x) = \sqrt{\frac{n!}{n'!}} (ix)^{n'-n} L_n^{n'-n}(x^2) e^{-x^2}, \quad (72)$$

where $L_n^{n'-n}$ is the generalized Laguerre polynomial of degree n . Similarly,

$$\langle 0 X' p'_z | e^{i\mathbf{q}\mathbf{r}} | N X p_z \rangle = \frac{1}{\sqrt{2}} \delta_{X', X+q_y l^2} \delta_{p'_z, p_z + q_z} \exp \left[i q_x \frac{(X + X')}{2} - i\varphi |N| \right] \left(1 + \frac{v p_z}{E_N} \right)^{1/2} L_{0, |N|}. \quad (73)$$

Substitution of Eq. (71) or Eq. (73) into Eq. (70) and subsequent integration over the polar angle φ (assuming spherical symmetry of $u_{\mathbf{q}}$) makes the proper vertex proportional to $\delta_{|N|+|N''|, |N'|+|N'''|}$ at $X = X'''$, that is, at $X = X'''$ the four-fermion vertex conserves the absolute Landau level number. For that reason, diagrams in the ladder series depicted in Fig. 2 starting from the fourth one all vanish. For the same reason, also the second diagram vanishes. So, one only needs to evaluate the first and the third diagrams in Fig. 2. In what follows, we show that also the third diagram vanishes to the first nontrivial order in powers of ω_c^{-1} . The first one has already been evaluated in Ref. [1]. For the sake of completeness, we reiterate this calculation here too.

Everywhere below we will suppress the disorder averaging brackets in the notation for the Green functions assuming they are already disorder averaged, *i.e.*,

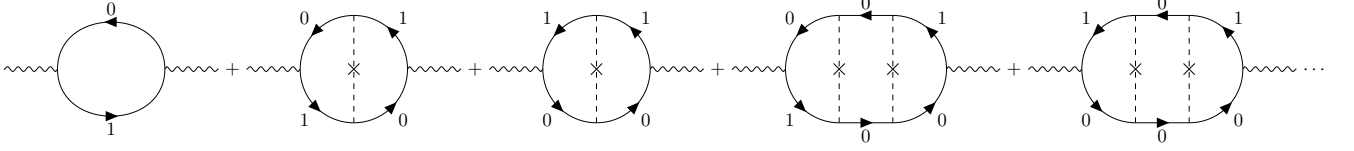


FIG. 2. The ladder series of Feynman diagrams contributing to conductivity to first nontrivial order in powers of ω_c^{-1} . The labels on the internal lines display the absolute value of the Landau level number

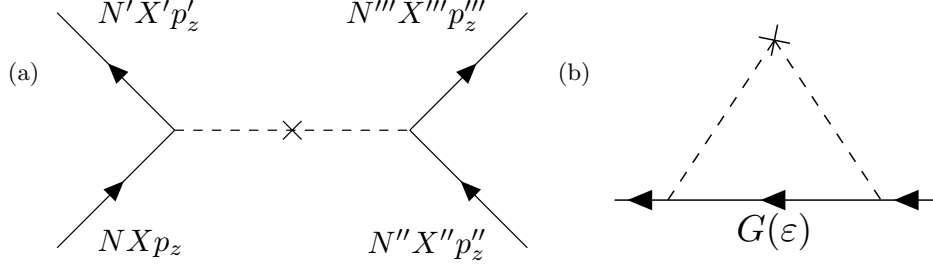


FIG. 3. Panel (a) The proper four-fermion vertex part to first Born approximation. Panel (b) Self-energy operator in the first (self-consistent) Born approximation

$$G(\epsilon) = \left\langle \frac{1}{\epsilon - \mathcal{H}} \right\rangle_s, \quad (74)$$

where $\mathcal{H} = v\boldsymbol{\sigma}(\mathbf{p} - (e/c)\mathbf{A}) + U = \mathcal{H}_0 + U$, with U the disorder potential. Defining the self-energy operator $\Sigma(\epsilon)$ via the equation $G(\epsilon) = (\epsilon - \mathcal{H}_0 - \Sigma(\epsilon))^{-1}$, within the self-consistent Born approximation the self-energy is given by the diagram in Fig. 3 (b), *i.e.*

$$\Sigma(\epsilon) = \langle UG(\epsilon)U \rangle_s. \quad (75)$$

Due to the uniformity of distribution of scattering centers, the matrix elements of $\Sigma(\epsilon)$ [and, consequently, of $G(\epsilon)$] will be diagonal in quantum numbers X, p_z and will be independent of X . Within the self-consistent Born approximation, due to the conservation of the absolute Landau level number by the proper four-fermion vertex, $\Sigma(\epsilon)$ will also be diagonal in $|N|$, but not necessarily in N itself. For Landau levels ± 1 let us introduce a 2×2 matrix $G_{1p_z}(\epsilon)$ whose matrix elements are defined as

$$[G_{1p_z}(\epsilon)]_{\sigma\sigma'} = \left\langle \left\langle \sigma X p_z \left| \frac{1}{\epsilon - \mathcal{H}} \right| \sigma' X p_z \right\rangle \right\rangle_s. \quad (76)$$

Here, σ and σ' are equal to ± 1 , the internal brackets stand for quantum mechanical averaging and the external for disorder averaging. The corresponding self-energy matrix $\Sigma_{1p_z}(\epsilon)$ is defined such that $G_{1p_z} = [\epsilon - E_1(p_z)\sigma_z - \Sigma_{1p_z}]^{-1}$ [here, $E_1(p_z)\sigma_z$ is a matrix with the unperturbed energy values of Landau levels ± 1 on the diagonal]. Also for the zeroth Landau level introduce

$$G_{0p_z} = \left\langle \left\langle 0X p_z \left| \frac{1}{\epsilon - \mathcal{H}} \right| 0X p_z \right\rangle \right\rangle_s. \quad (77)$$

To lowest nontrivial order in powers of ω_c^{-1} the equation for Σ_{1p_z} , which is just the projection of Eq. (75) on Landau levels ± 1 , has the form,

$$[\Sigma_{1p_z}(\varepsilon)]_{\sigma\sigma'} = \sum_{X'p'_z} \left\langle \langle \sigma X p_z | U | 0 X' p'_z \rangle \langle 0 X' p'_z | U | \sigma' X p_z \rangle \right\rangle_s G_{0p'_z}(\varepsilon). \quad (78)$$

Now we have all the ingredients necessary for the calculation of σ_{xx} . The contribution of the first diagram in Fig. 2 to σ_{xx} equals

$$\Delta\sigma_{xx}^{(1)} = 4v^2 e^2 V^{-1} \int \frac{d\varepsilon}{2\pi} \left(-\frac{\partial f}{\partial \varepsilon} \right) \text{tr} \left[\sigma_x \mathfrak{I}m G(\varepsilon + i0) \sigma_x \mathfrak{I}m G(\varepsilon + i0) \right]_{O(\omega_c^{-2})}, \quad (79)$$

where $\mathfrak{I}m G(\varepsilon + i0) = (1/2i)[G(\varepsilon + i0) - G(\varepsilon - i0)]$ and the subscript $O(\omega_c^{-2})$ means that only the contribution of order ω_c^{-2} needs to be extracted. A factor of 2 coming from spin degeneracy is also included. The evaluation of this term can be done by inserting the resolution of identity twice into this equation and keeping only the projectors on Landau levels 0 and ± 1 . Keeping in mind that $\langle \sigma X p_z | \sigma_x | 0 X p_z \rangle = (i/\sqrt{2})\sigma(1 - vp_z/E_\sigma)^{1/2}$ and neglecting vp_z/E_σ we obtain

$$\Delta\sigma_{xx}^{(1)} = 4v^2 e^2 V^{-1} \int \frac{d\varepsilon}{2\pi} \left(-\frac{\partial f}{\partial \varepsilon} \right) \sum_{\sigma\sigma'} \sum_{Xp_z} \sum_{X'p'_z} \sigma\sigma' \mathfrak{I}m G_{0p_z}(\varepsilon + i0) [\mathfrak{I}m G_{1p'_z}(\varepsilon + i0)]_{\sigma\sigma'}. \quad (80)$$

Taking into account that

$$G_{1p'_z}(\varepsilon) = (\varepsilon - \sigma_z E_1(p'_z))^{-1} + (\varepsilon - \sigma_z E_1(p'_z))^{-1} \Sigma_{1p_z}(\varepsilon) (\varepsilon - \sigma_z E_1(p'_z))^{-1} + \dots, \quad (81)$$

the imaginary part $\mathfrak{I}m G_{1p'_z}(\varepsilon + i0) = \omega_c^{-2} \sigma_z \mathfrak{I}m \Sigma_{1p_z}(\varepsilon + i0) \sigma_z$ to order ω_c^{-2} . Using Eq. (78) we obtain

$$\begin{aligned} \Delta\sigma_{xx}^{(1)} = (4v^2 e^2 / \omega_c^2) V^{-1} \int \frac{d\varepsilon}{2\pi} \left(-\frac{\partial f}{\partial \varepsilon} \right) \sum_{\sigma\sigma'} \sum_{Xp_z} \sum_{X'p'_z} \mathfrak{I}m G_{0p_z}(\varepsilon + i0) \mathfrak{I}m G_{0p'_z}(\varepsilon + i0) \\ \times \left\langle \langle \sigma X p_z | U | 0 X' p'_z \rangle \langle 0 X' p'_z | U | \sigma' X p_z \rangle \right\rangle_s. \end{aligned} \quad (82)$$

The contribution to σ_{xx} of the second and third diagrams in Fig. 2 is given by the expression (with spin degeneracy taken into account)

$$\begin{aligned} \Delta\sigma_{xx}^{(2,3)} = 2e^2 v^2 V^{-1} \int \frac{d\varepsilon}{(2\pi)} \left(-\frac{\partial f}{\partial \varepsilon} \right) \left[\text{Re tr} \left\langle \sigma_x G(\varepsilon + i0) U G(\varepsilon + i0) \sigma_x \right. \right. \\ \left. \left. \times \left[G(\varepsilon - i0) U G(\varepsilon - i0) - G(\varepsilon + i0) U G(\varepsilon + i0) \right] \right\rangle_s \right]_{O(\omega_c^{-2})}. \end{aligned} \quad (83)$$

We now insert resolutions of identity and keep only projectors on Landau levels 0 and ± 1 . Furthermore, we neglect $vp_z/E_{\pm 1}$ in the matrix elements of σ_x , while keeping only the first term in Eq. (81). The latter is enough because there must always be two G_{1p_z} lines, see Fig. (2). We obtain

$$\begin{aligned} \Delta\sigma_{xx}^{(2,3)} = -(2e^2 v^2 / \omega_c^2) V^{-1} \int \frac{d\varepsilon}{2\pi} \left(-\frac{\partial f}{\partial \varepsilon} \right) \sum_{\sigma\sigma'} \sum_{XX'} \sum_{p_z p'_z} \mathfrak{I}m G_{0p_z}(\varepsilon + i0) \mathfrak{I}m G_{0p'_z}(\varepsilon + i0) \\ \times \left\langle \langle \sigma' X' p'_z | U | 0 X p_z \rangle \langle \sigma X p_z | U | 0 X' p'_z \rangle + \text{c.c.} \right\rangle_s \end{aligned} \quad (84)$$

where c.c. stands for complex conjugate. Note that after disorder averaging this contribution vanishes because of the conservation of the absolute Landau level number by the proper four-fermion vertex. Such vanishing of the vertex corrections is a special property of the zeroth Landau level.

To show the equivalence between the Feynman diagram calculation and the center migration theory, we take the sum of Eqs. (82) and (84) before disorder averaging. Then, we introduce the ladder operator $a = (l^{-1}(x - X) + ilp_x)/\sqrt{2}$, which lowers the absolute Landau level number and annihilates the zeroth Landau level. Note that, neglecting $vp_z/E_{\pm 1}$, we can write for any $\sigma = \pm 1$

$$\langle \sigma X p_z | U | 0 X' p'_z \rangle = \langle 0 X p_z | \frac{a}{\sqrt{2}} U | 0 X' p'_z \rangle \quad (85)$$

and similarly for complex conjugated matrix elements. Then the sum of Eqs. (82) and (84) can be written as

$$\sigma_{xx} = (8e^2 v^2 / \omega_c^2) V^{-1} \int \frac{d\varepsilon}{2\pi} \left(-\frac{\partial f}{\partial \varepsilon} \right) \sum_{X p_z X' p'_z} \Im G_{0p_z}(\varepsilon + i0) \Im G_{0p'_z}(\varepsilon + i0) \left\langle \left| \left\langle 0 X p_z \left| \left[\frac{a + a^\dagger}{\sqrt{2}}, U \right] \right| 0 X' p'_z \right\rangle \right|^2 \right\rangle_s. \quad (86)$$

Noting that $(a + a^\dagger)/\sqrt{2} = (x - X)/l$, where $X = l^2 p_y$ is the center position operator, also that $\Im G_{0p_z}(\varepsilon + i0) = -\pi \delta(\varepsilon - E_0(p_z))$ and $\omega_c = \sqrt{2}v/l$, and integrating with respect to ε , we obtain Eq. (9).

CONCLUSION

In this paper we presented a simpler derivation of Abrikosov's quantum magnetoresistance, based on the picture of diffusing cyclotron centers. It is better suited for the calculation of magnetoresistance in the extreme quantum limit because it admits a natural restriction of dynamics to a single Landau level, is very intuitive and allows the whole calculation to be reduced just to single application of the Fermi golden rule. Furthermore, in a random potential smooth on the scale of the magnetic length, the cyclotron centers drift according to classical laws, which together with the linear-in- H density of states leads to a linear magnetoresistance for a compensated Weyl semimetal in three dimensions.

Another advantage of this approach is that it works equally well for a two-dimensional model too. In particular, for undoped graphene, a smooth random potential will also give rise to a linear magnetoresistance.

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